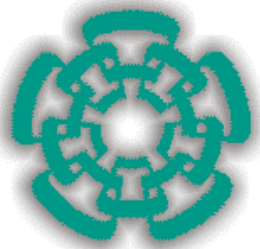


Estudios Ópticos en el Procesamiento de Películas Delgadas

Arturo Mendoza Galván

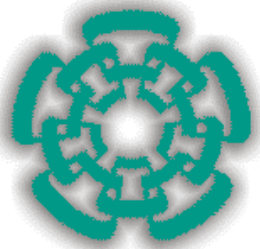
CINVESTAV-IPN, Unidad Querétaro

**I Taller Internacional de Ciencia de Materiales
Universidad Autónoma de Puebla
Instituto de Física “Luis Rivera Terrazas”
Enero de 2005**

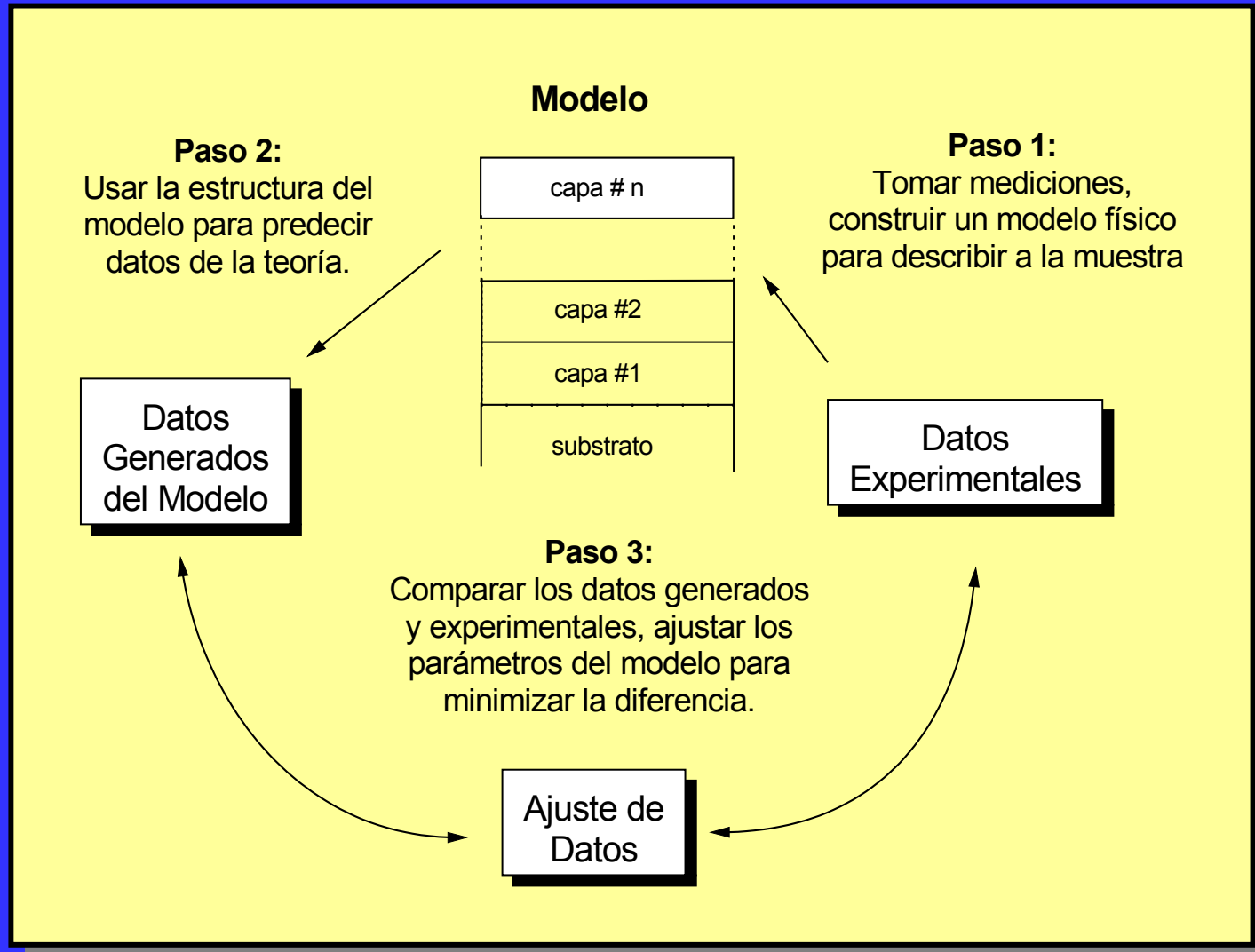


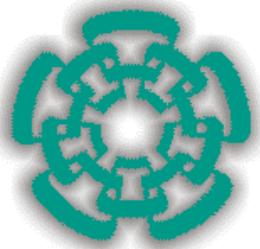
Contenido:

- 1. ITO: Efecto de la temperatura de tratamiento. *Cuauhtémoc Trejo (M) y Miguel Gracia (IFUAP).***
- 2. Co-SiO₂: Efectos de composición y temperatura de tratamiento. *Alicia Ramos (M) y Hugo Tototzintle (M).***
- 3. Ni-SiO₂: Efectos de composición y temperatura de tratamiento. *Julián Hernández (D).***
- 4. Oxidación de Ni. *Ana María López (D).***



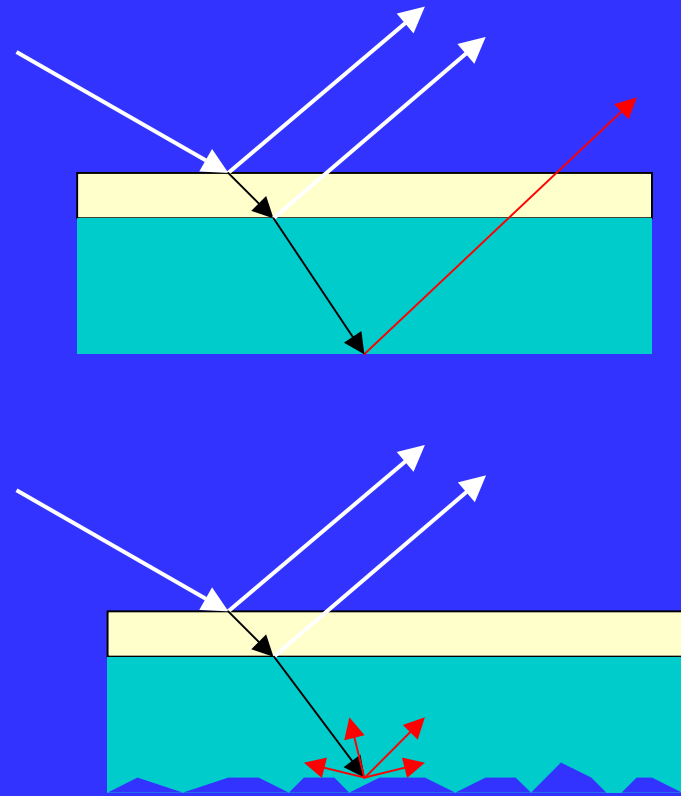
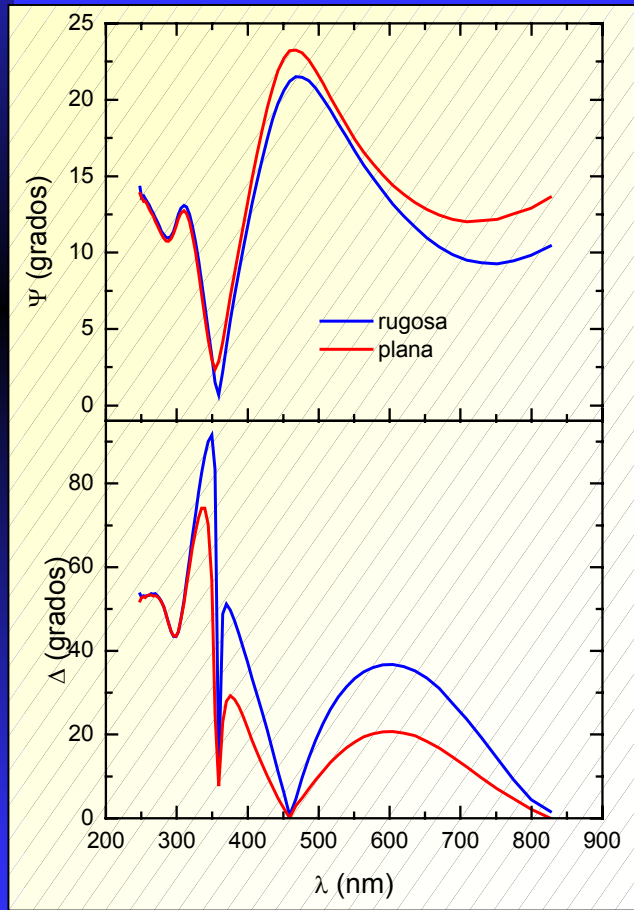
Análisis de Datos

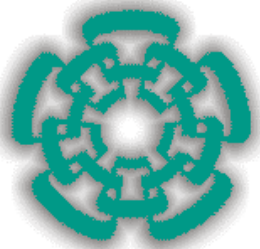




Ejemplos: Efecto de reflexiones en la cara posterior del sustrato sobre las mediciones elipsométricas.

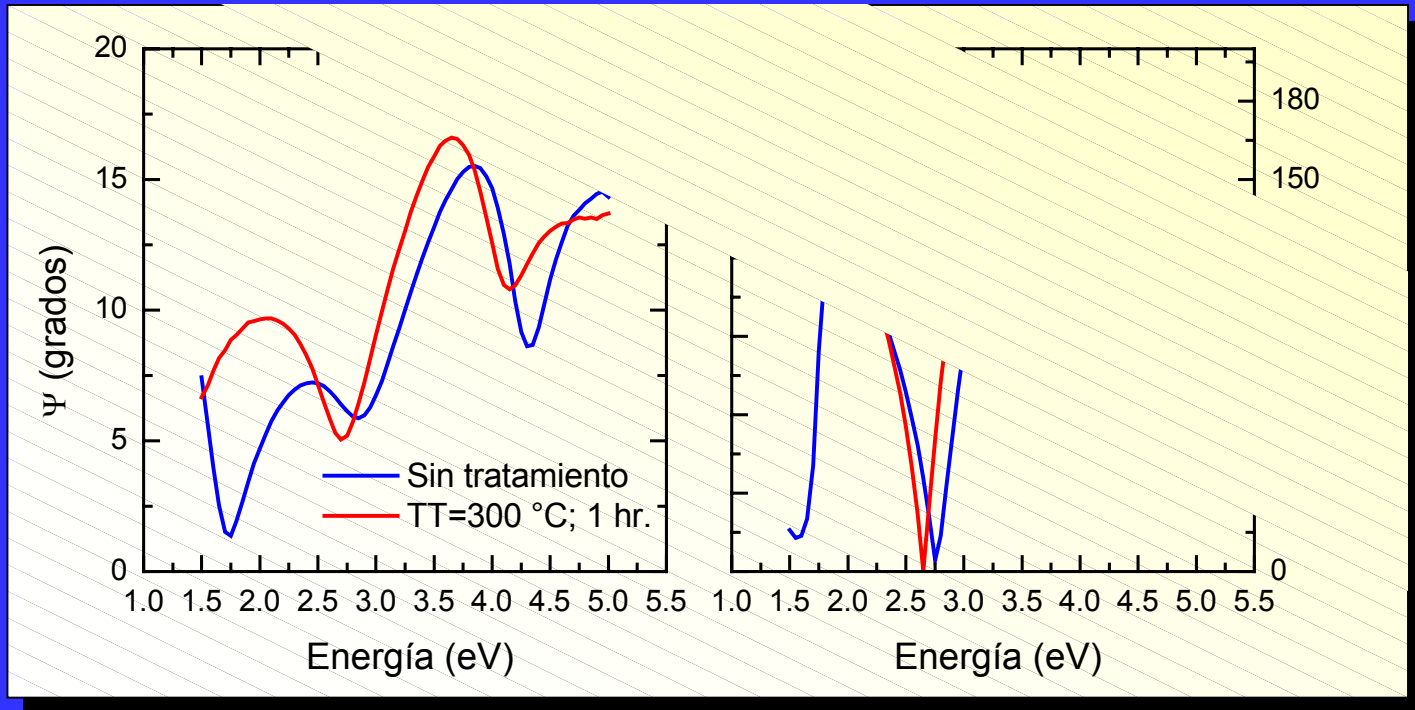
- Óxido de indio estaño (ITO) sobre vidrio

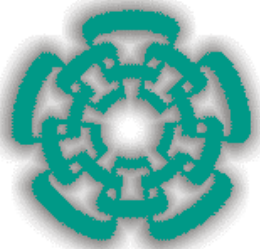




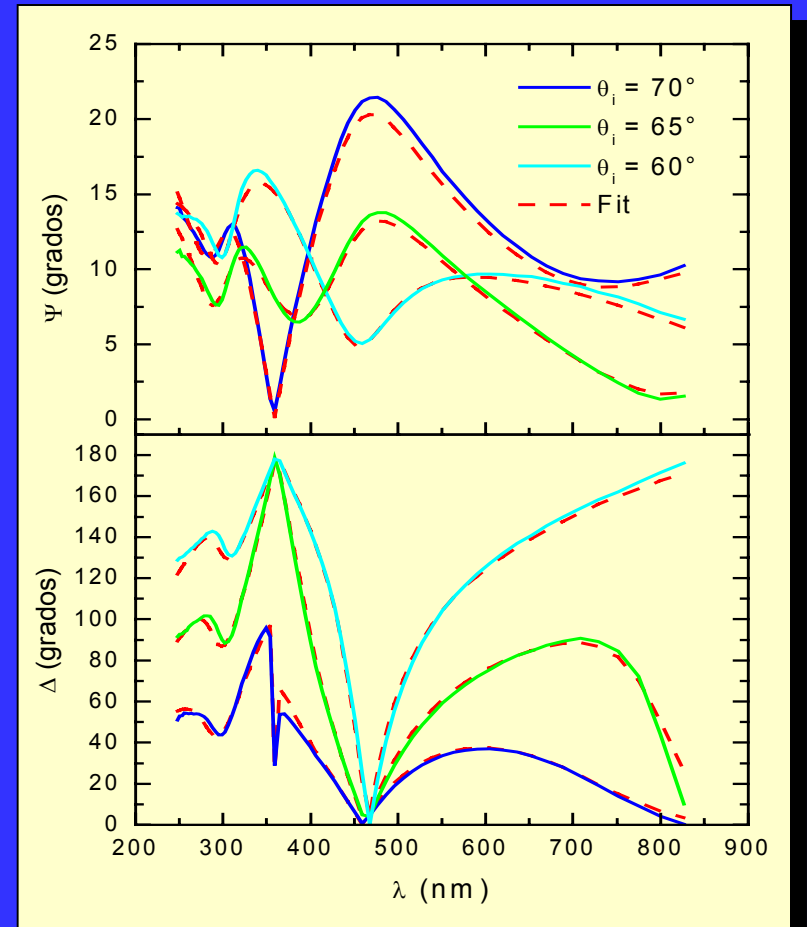
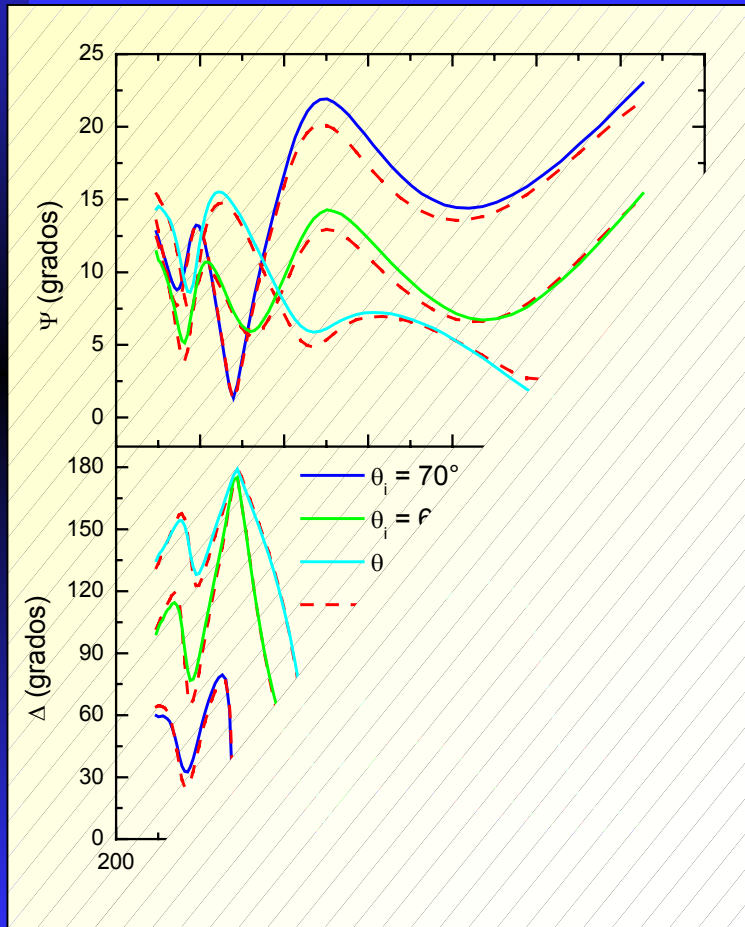
Ejemplos: ITO sobre vidrio

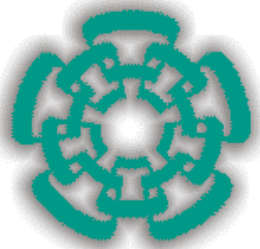
Datos experimentales





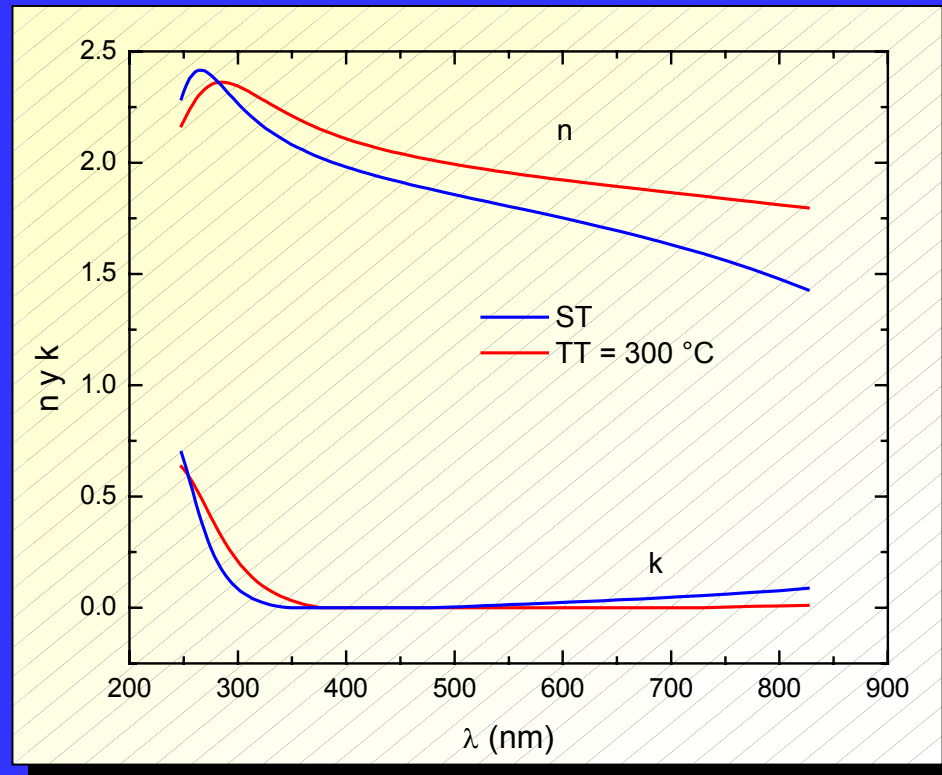
Ajustes para tres ángulos de incidencia

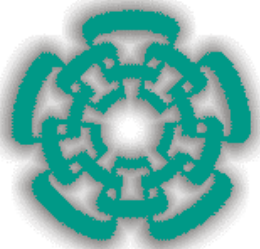




Efecto sobre las constantes ópticas del ITO

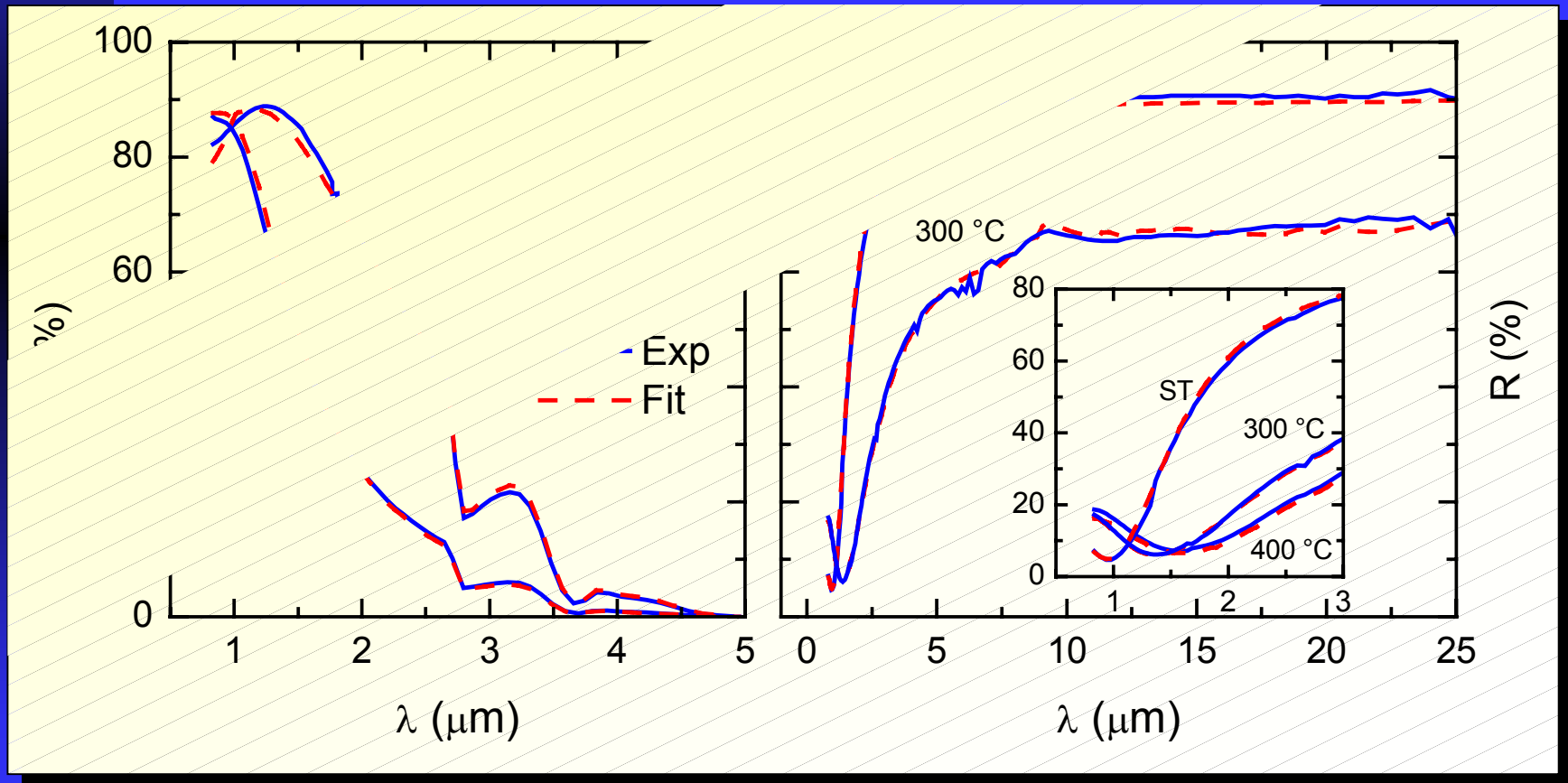
Oscilador de Lorentz generalizado

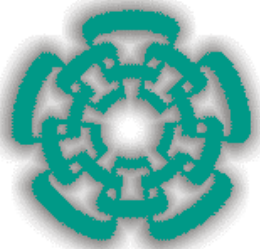




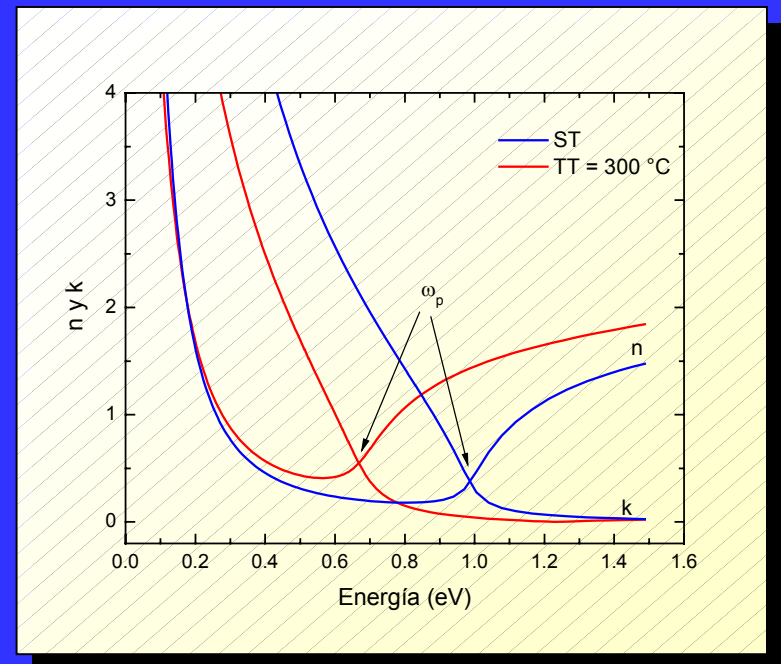
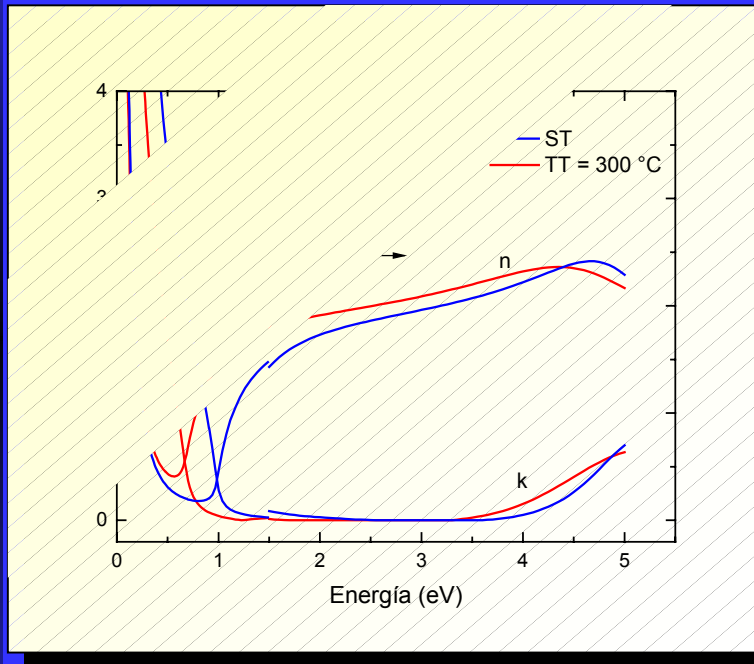
Ajustes de R y T en el infrarrojo

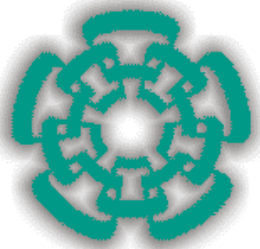
$$\varepsilon(\omega) = \varepsilon_{\infty} - \frac{\varepsilon_{\infty} \omega_p^2}{\omega(\omega + i\nu)} ; \quad \sigma_{IR} = \frac{\varepsilon_0 \varepsilon_{\infty} \omega_p^2}{\hbar \nu},$$





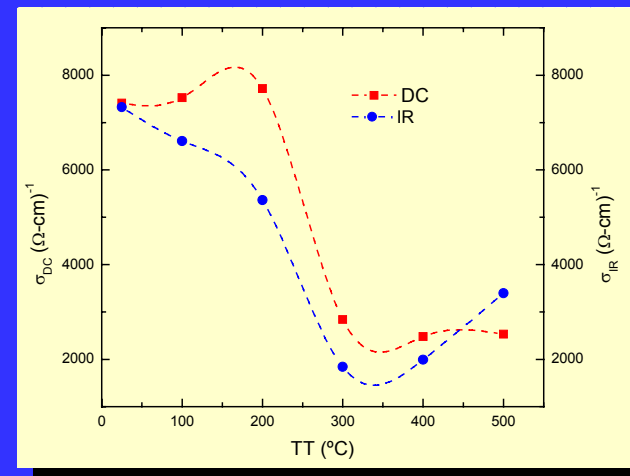
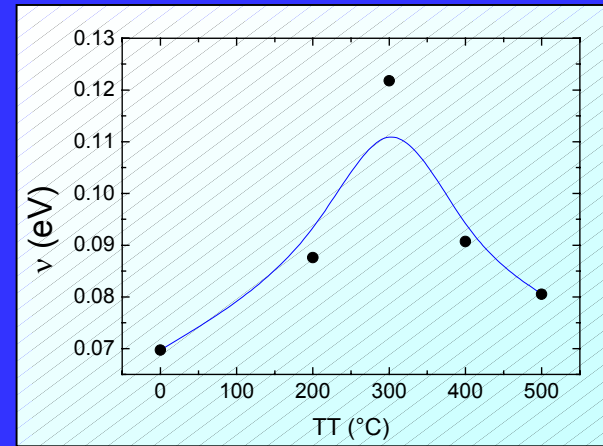
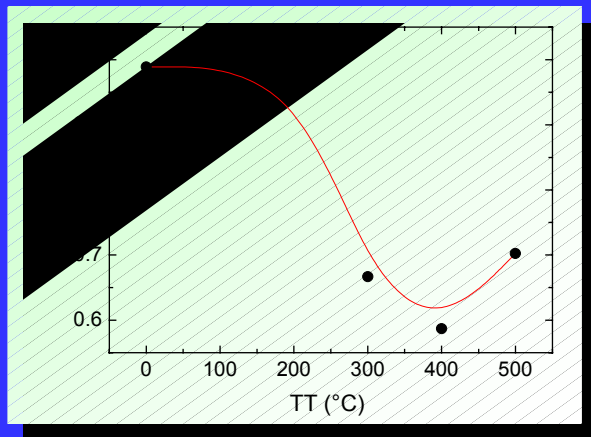
Constantes ópticas del ITO y frecuencia de plasma

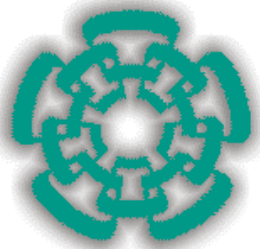




Parámetros de ajuste y conductividad eléctrica

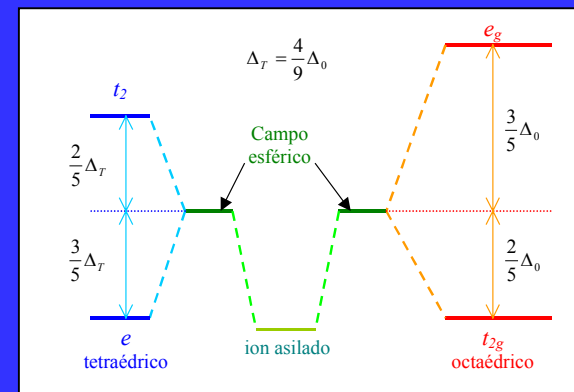
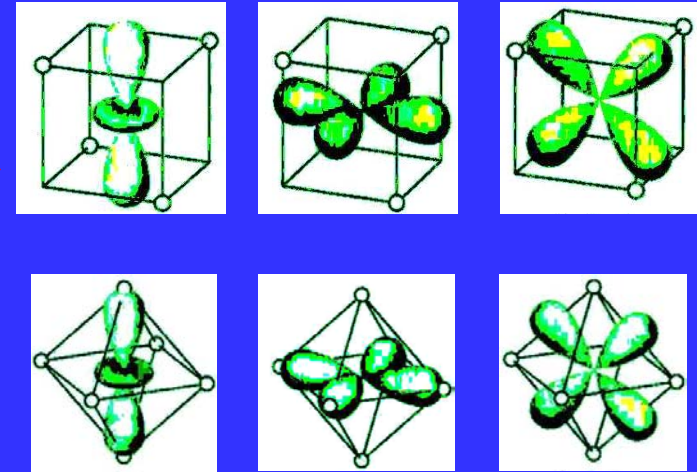
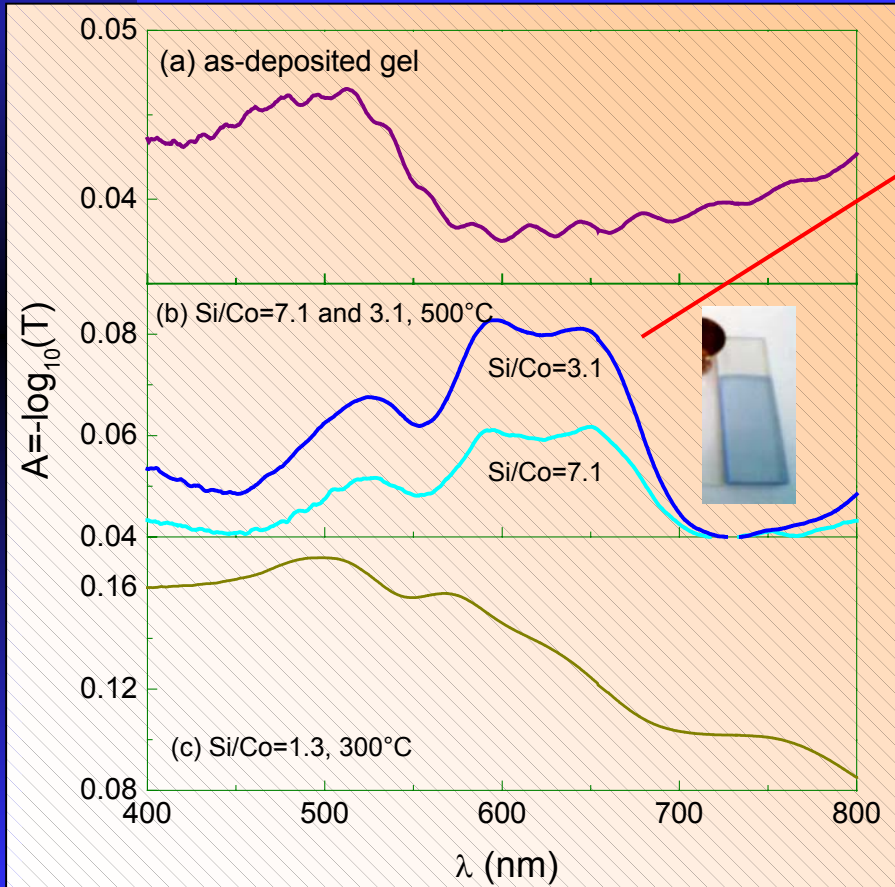
$$\varepsilon(\omega) = \varepsilon_{\infty} - \frac{\varepsilon_{\infty} \omega_p^2}{\omega(\omega + i\nu)}; \quad \sigma_{IR} = \frac{\varepsilon_0 \varepsilon_{\infty} \omega_p^2}{\hbar \nu},$$

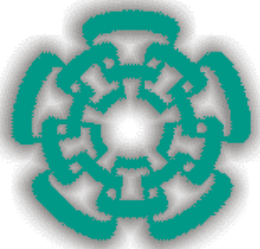




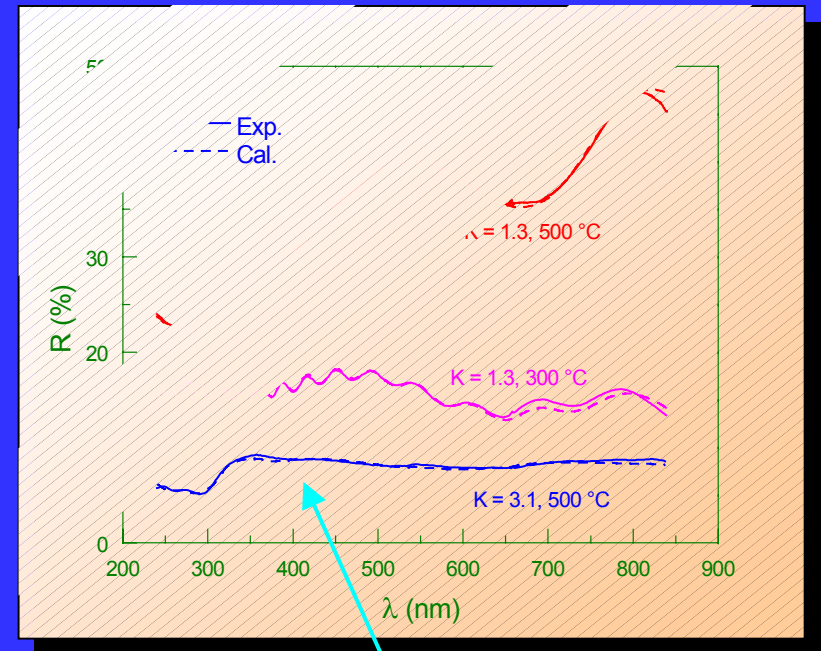
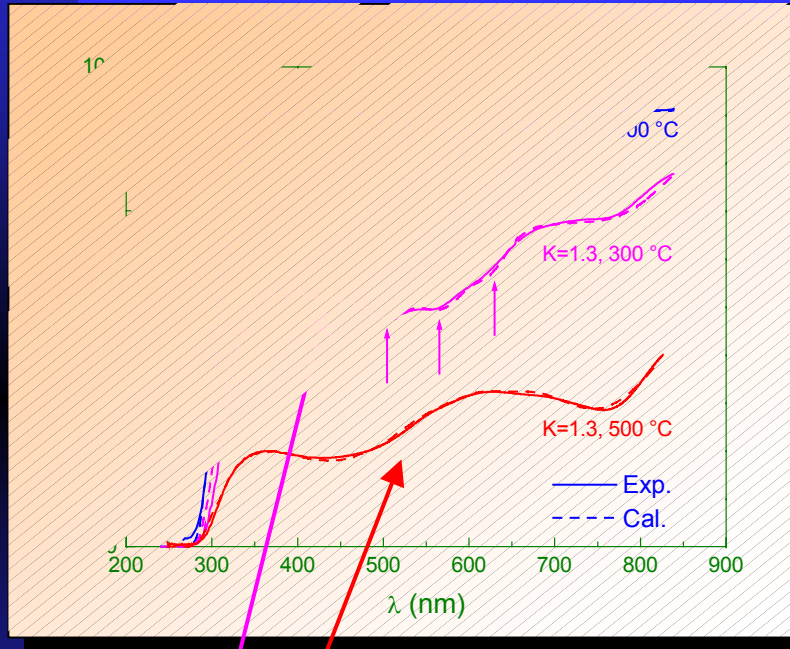
Películas compuestas Co-SiO₂

Sitios tetraédricos y octaédricos

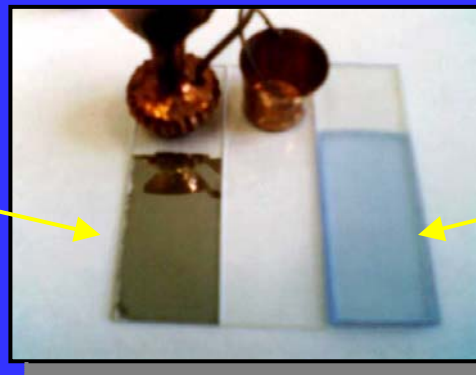




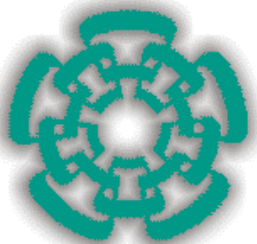
Películas compuestas Co-SiO₂



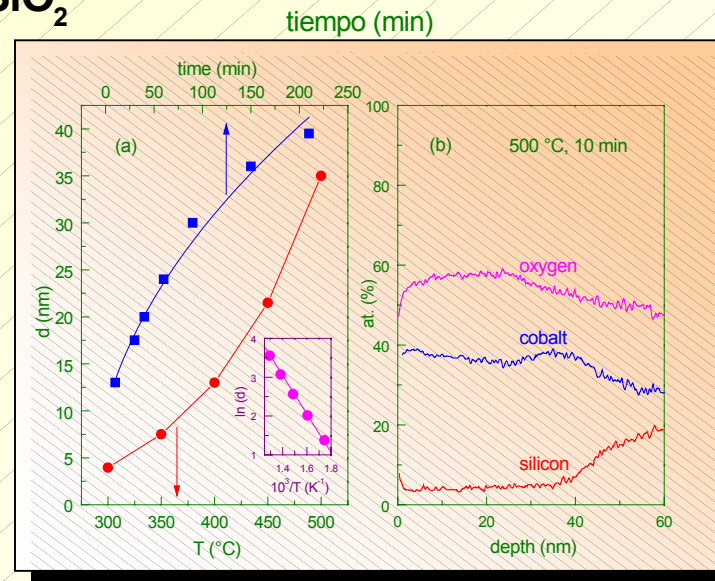
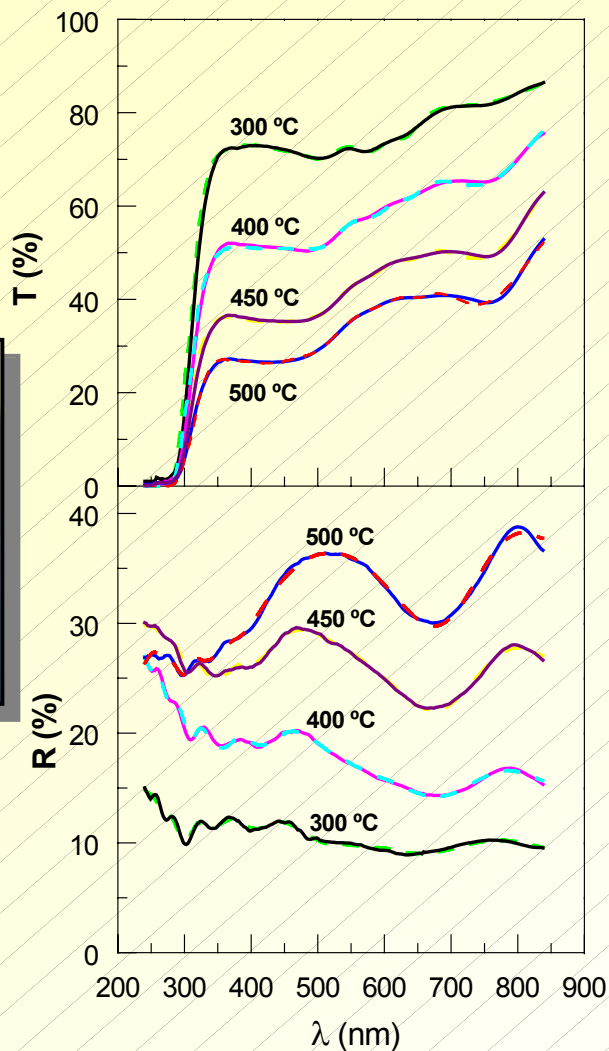
Co₃O₄
SiO₂:Co²⁺
vidrio



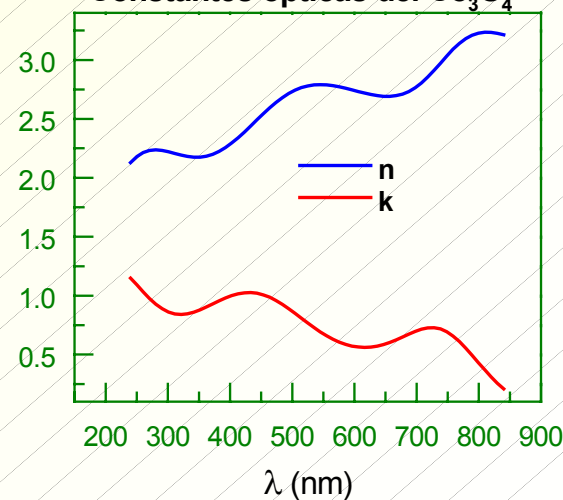
SiO₂:Co²⁺
vidrio

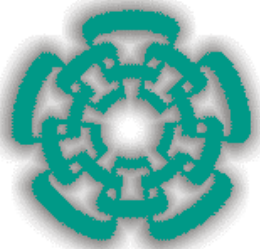


Formación de Co_3O_4 sobre SiO_2

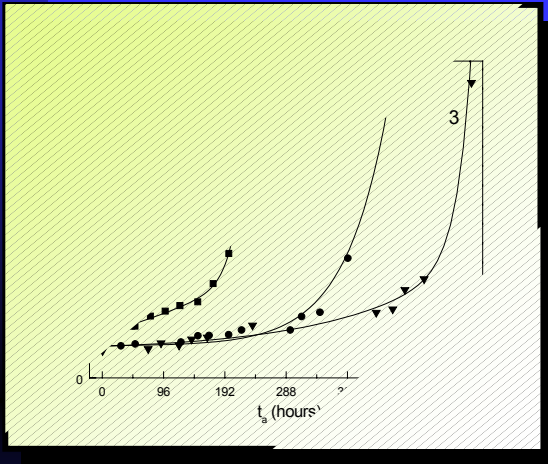


Constantes ópticas del Co_3O_4





Efecto de la viscosidad de la solución precursora. Formación de Co_3O_4 en la superficie y en el volumen de SiO_2 .



Co_3O_4

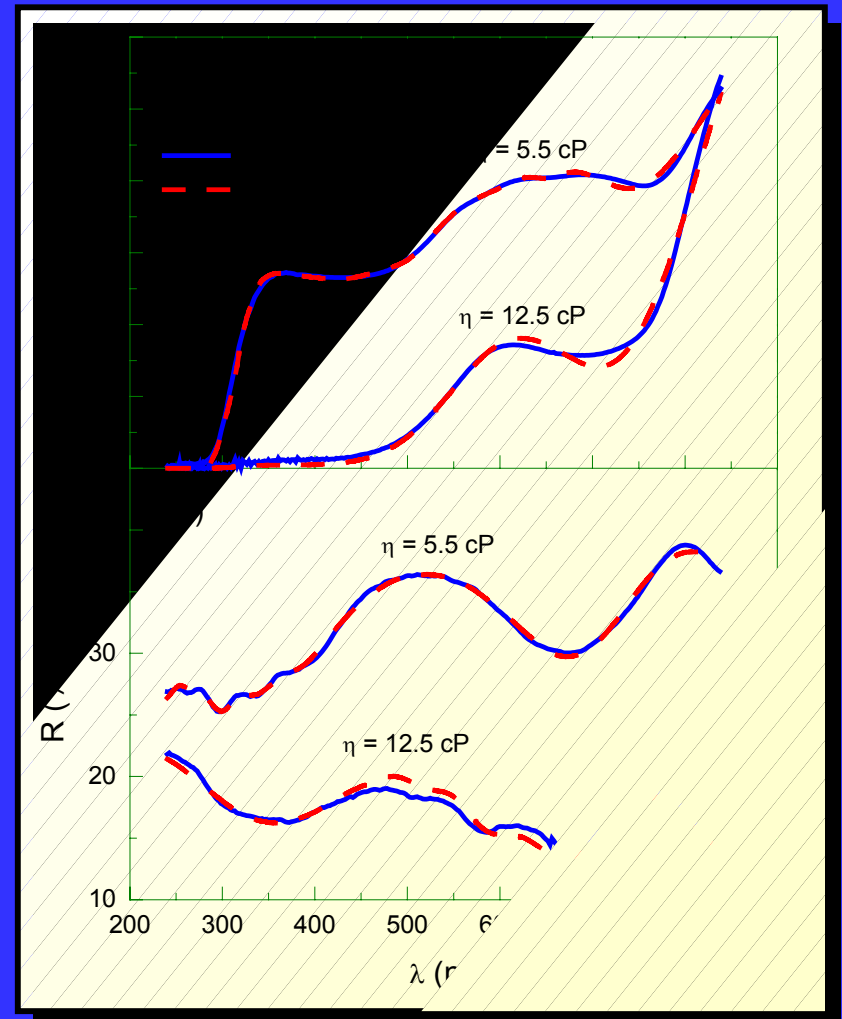
$\text{SiO}_2:\text{Co}^{2+}$

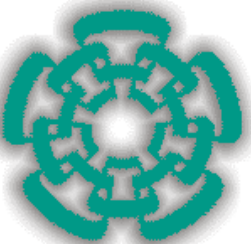
vidrio

SiO_2

vidrio

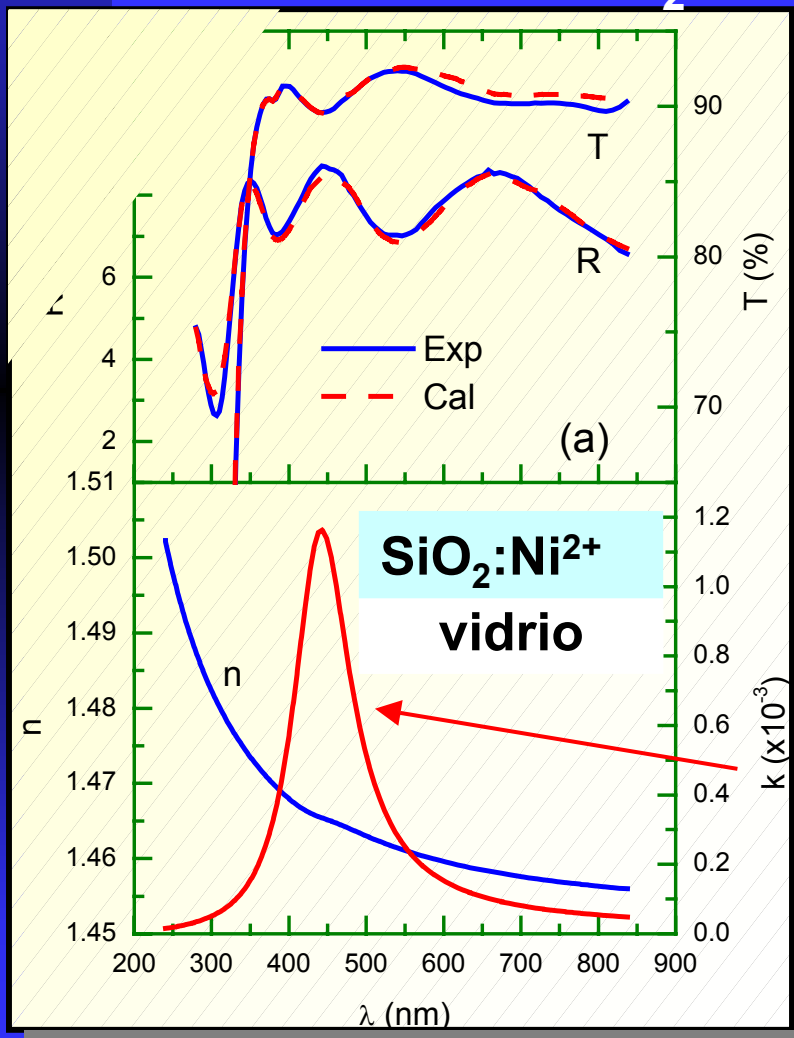
$$\frac{\varepsilon - \varepsilon_{\text{SiO}_2}}{\varepsilon + 2\varepsilon_{\text{SiO}_2}} = f_{\text{Co}_3\text{O}_4} \frac{\varepsilon_{\text{Co}_3\text{O}_4} - \varepsilon_{\text{SiO}_2}}{\varepsilon_{\text{Co}_3\text{O}_4} + 2\varepsilon_{\text{SiO}_2}}$$



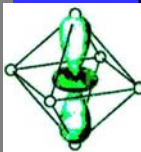
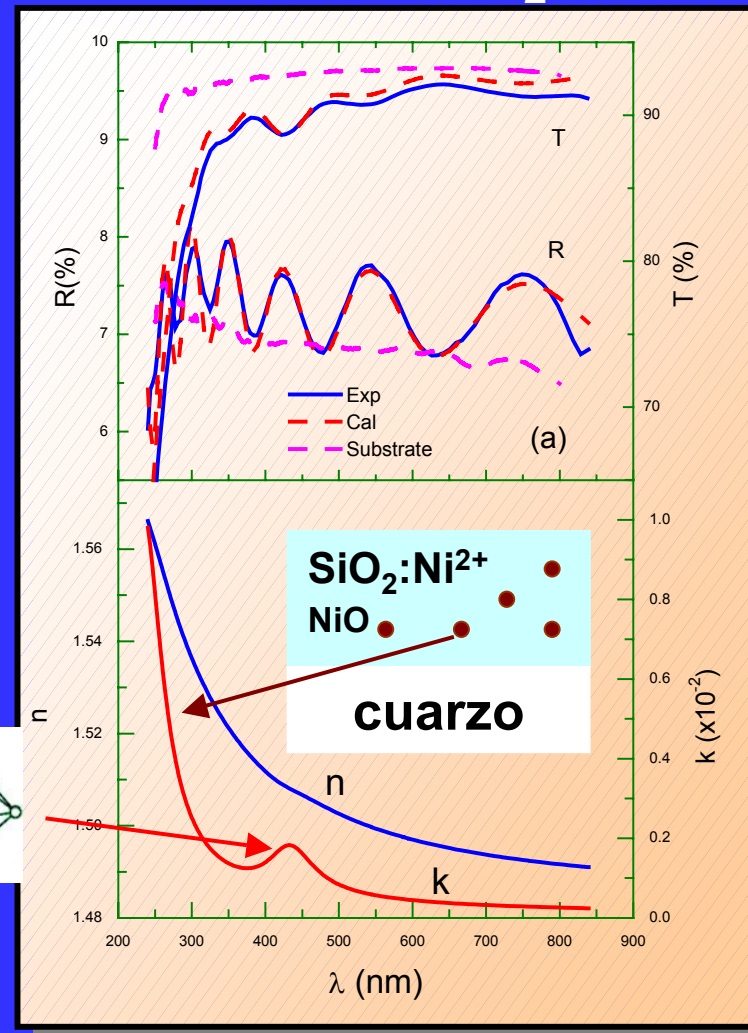


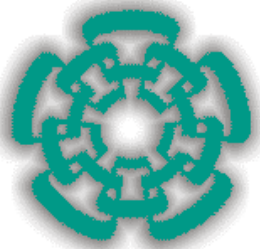
Compuestos Ni-SiO₂

10NiO+90SiO₂

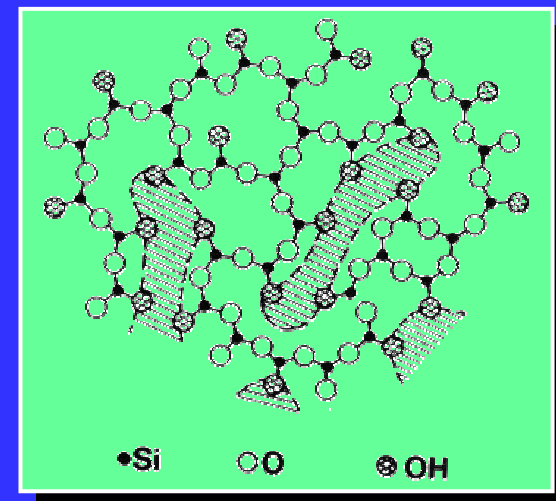
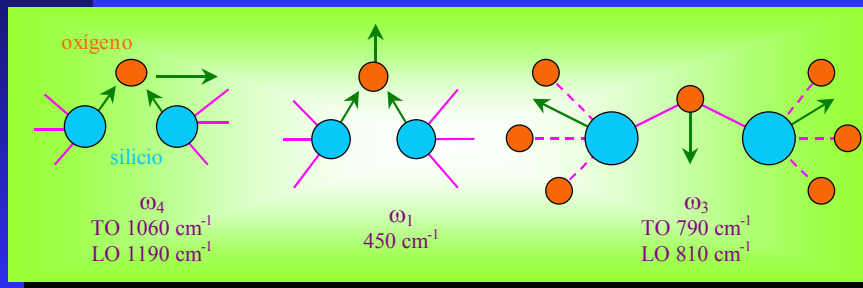
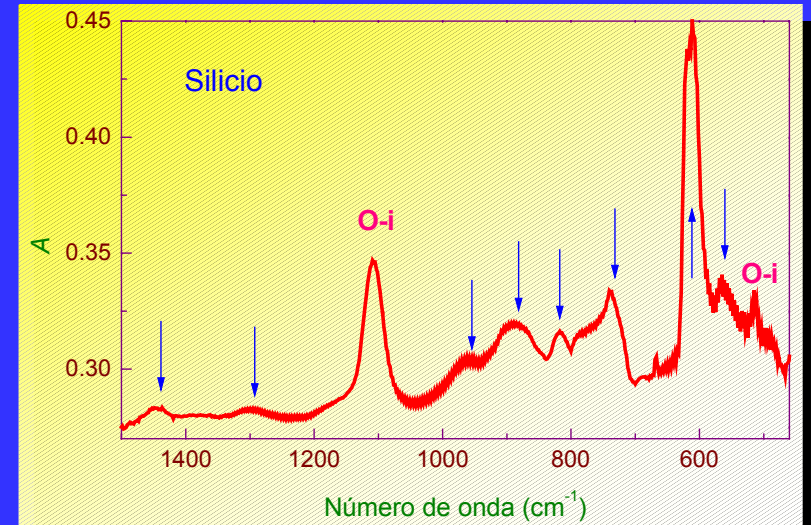
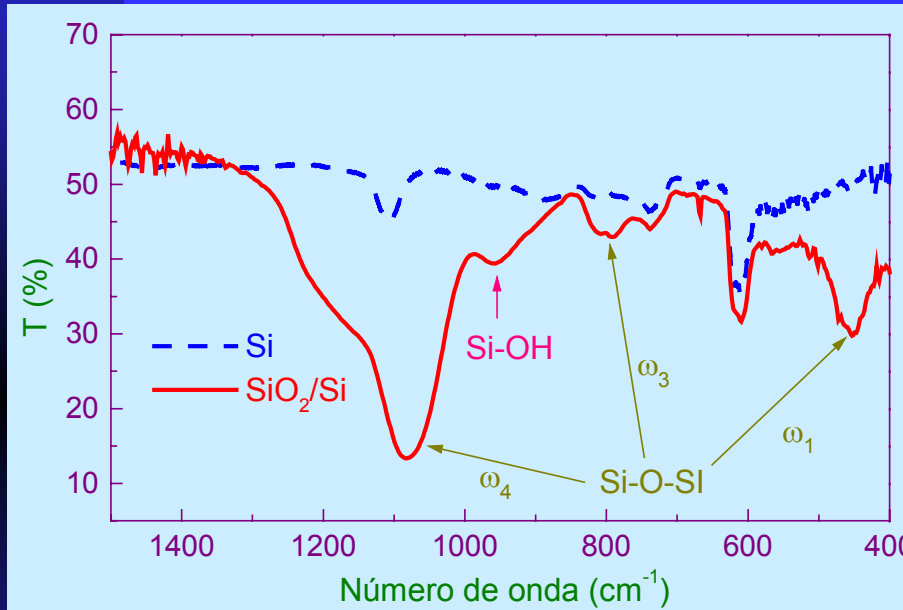


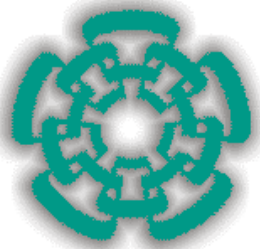
20NiO+80SiO₂





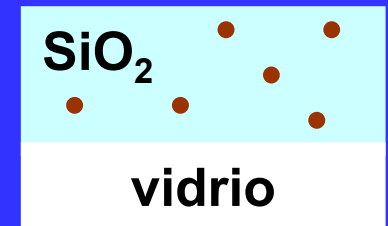
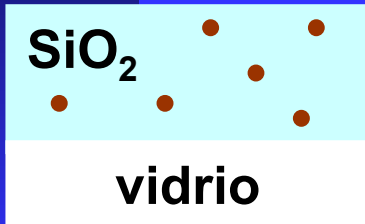
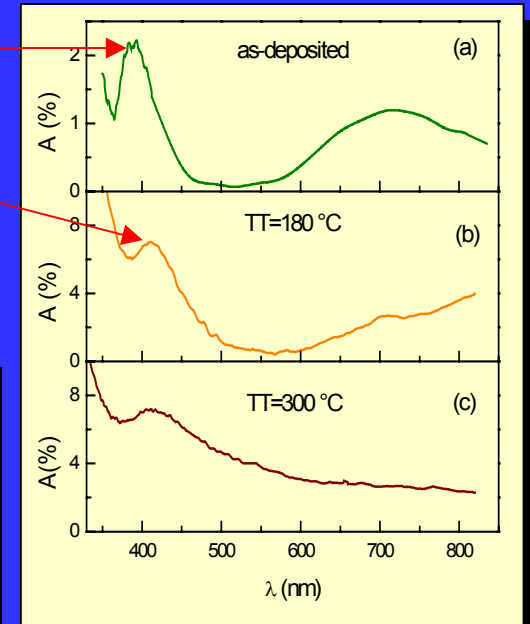
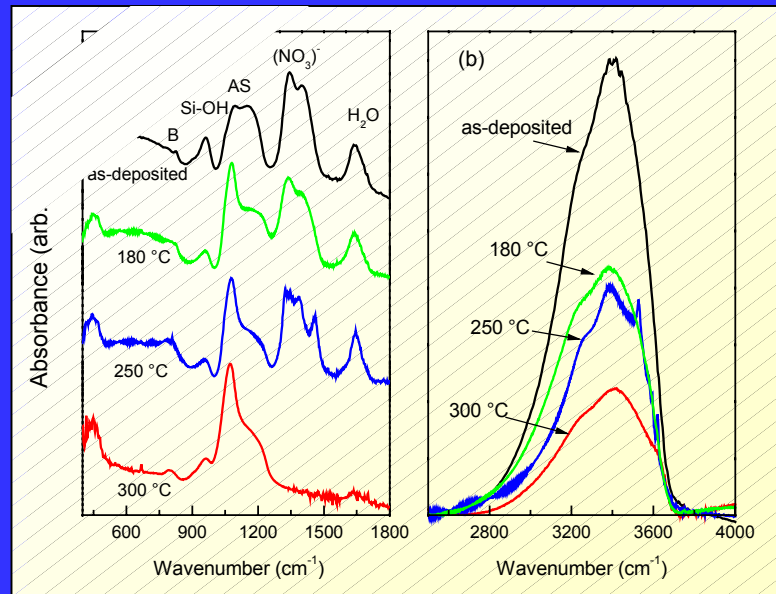
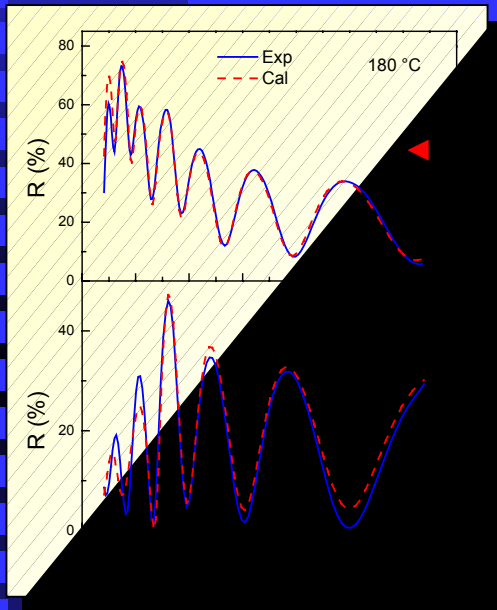
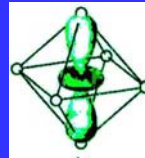
Infrarrojo: SiO₂ sobre Si

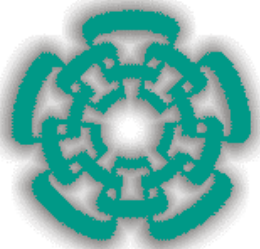




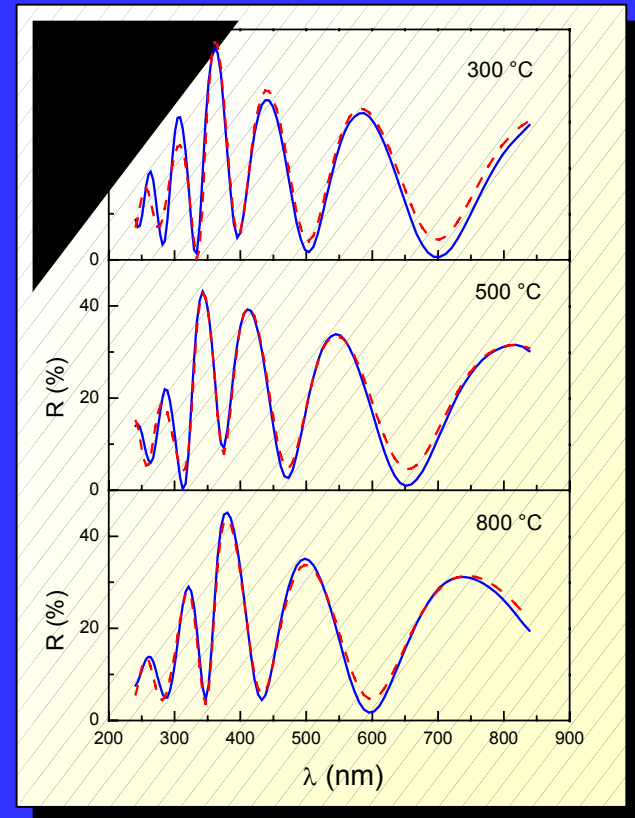
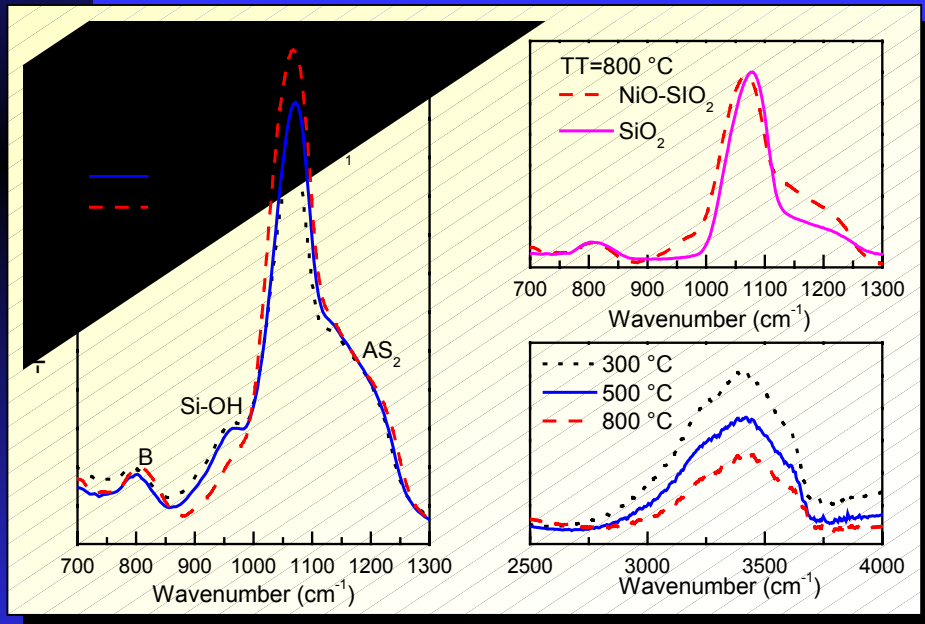
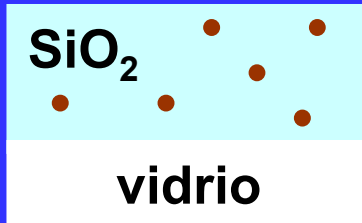
Compuestos Ni-SiO₂

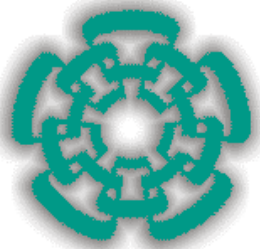
40NiO+60SiO₂





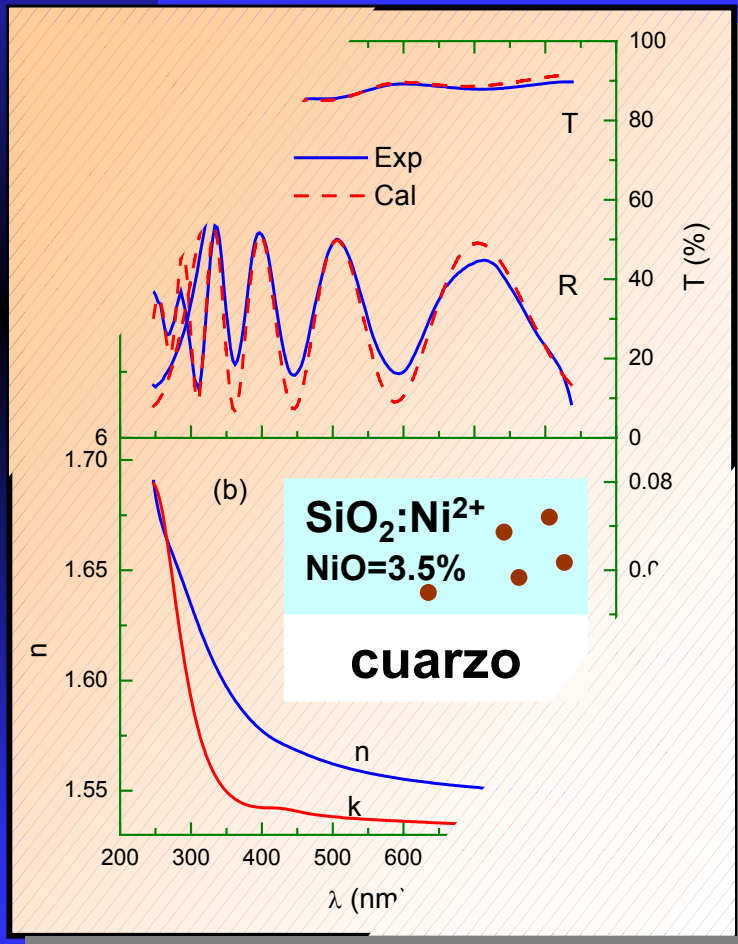
Formación de partículas de NiO en SiO₂





Transformación de partículas de NiO en partículas de Ni.

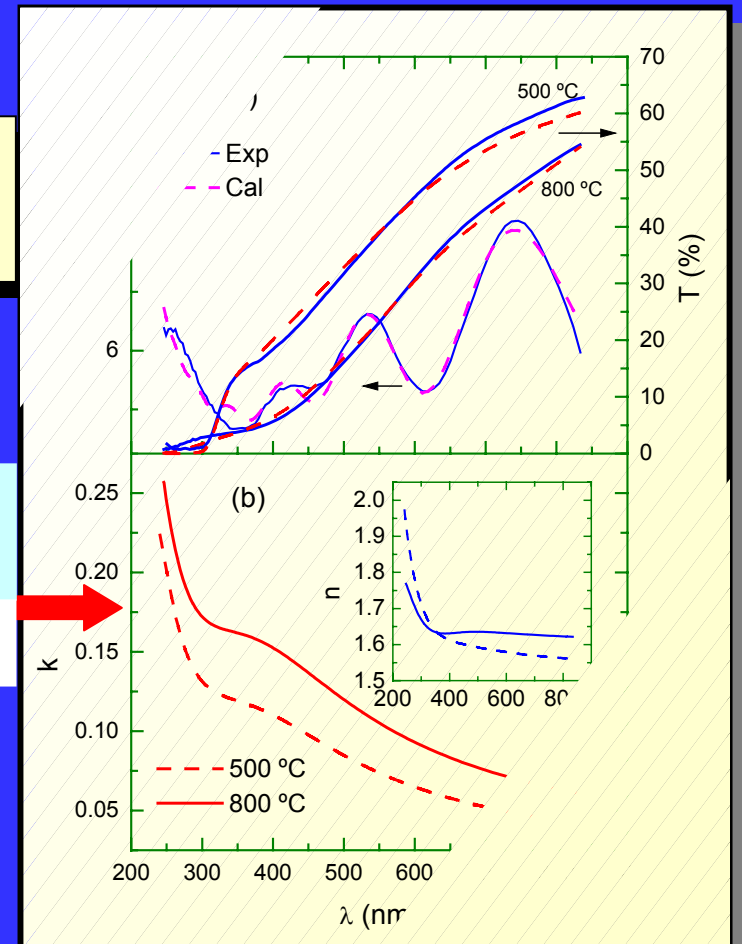
Tratamiento en aire a 500°C

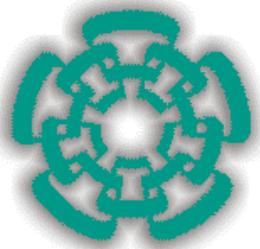


f
 $=5\text{nm}$

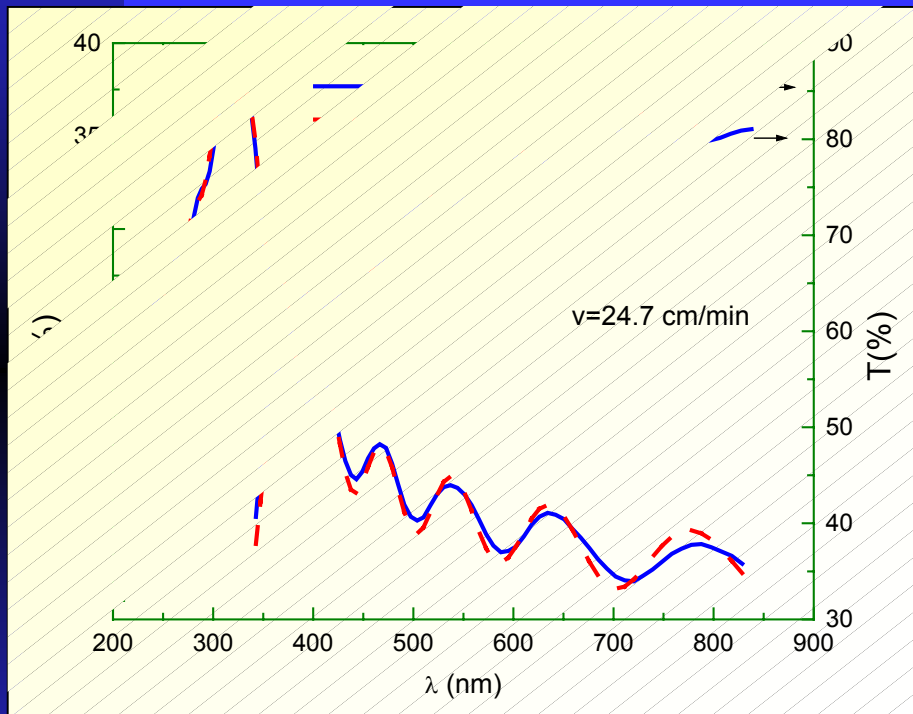
SiO_2
 Ni
cuarzo

Tratamiento en H_2/N_2





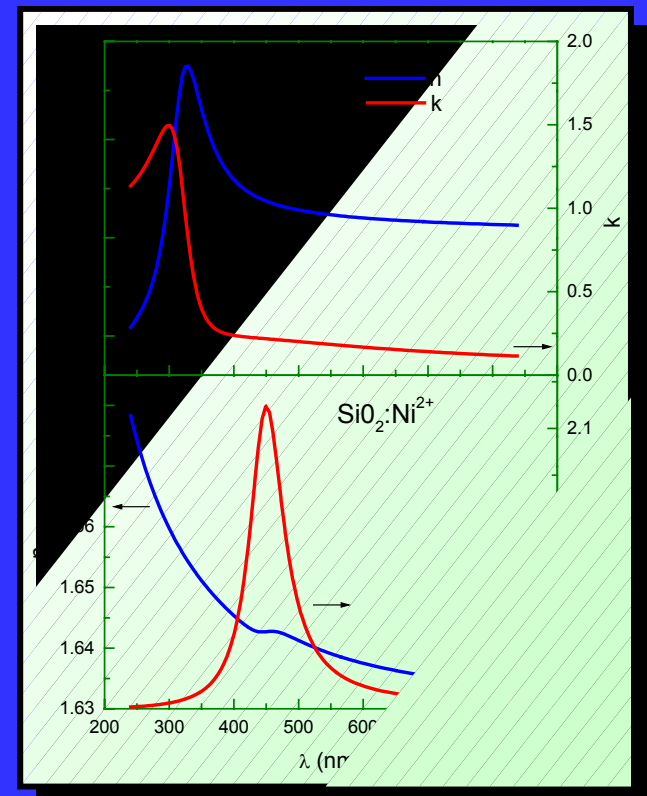
Formación de una capa superficial de NiO

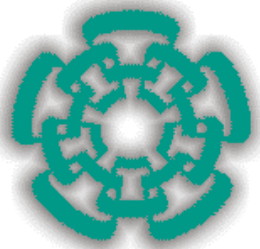


NiO, 22 nm

SiO₂:Ni²⁺, 1036 nm

vidrio





Oxidación de Níquel

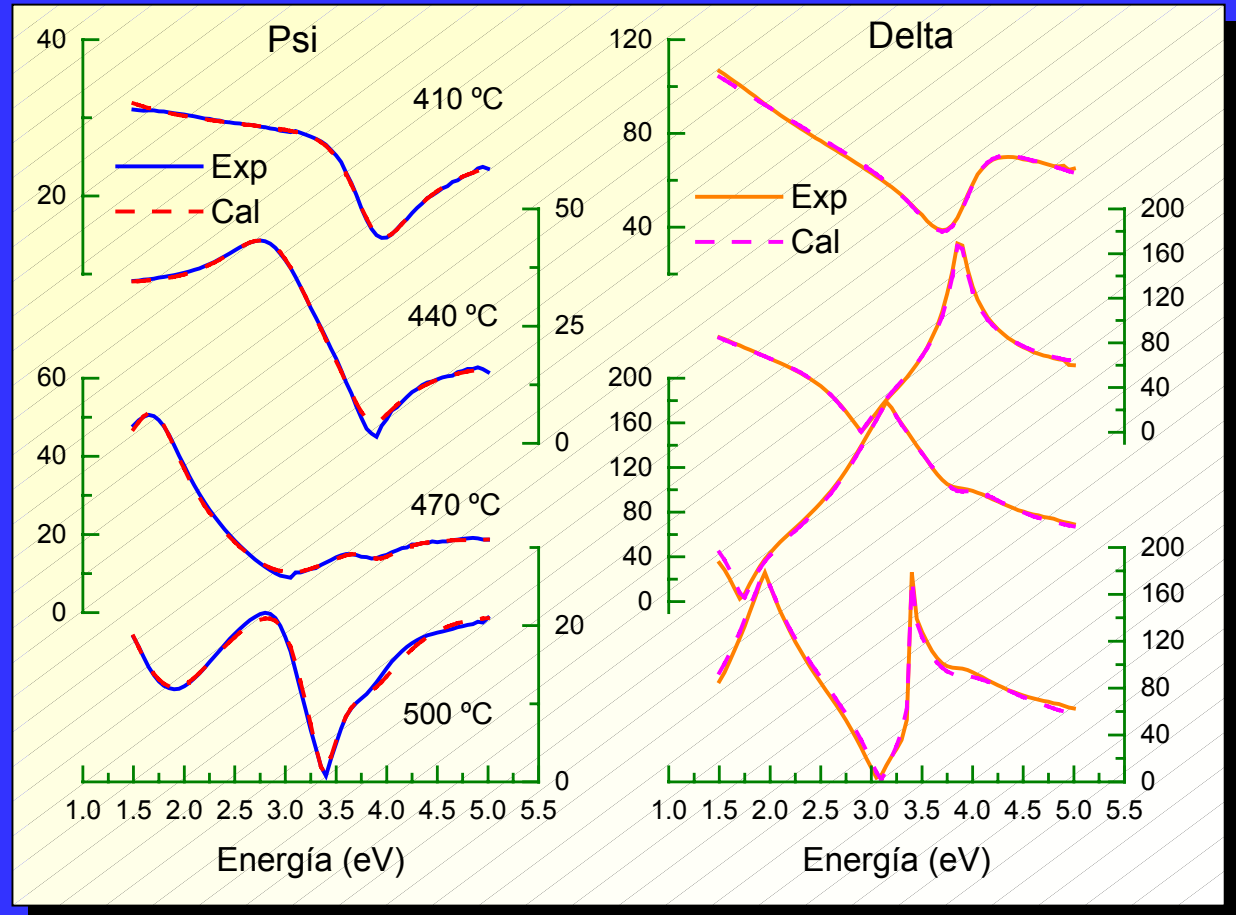
Ni:125 nm
vidrio

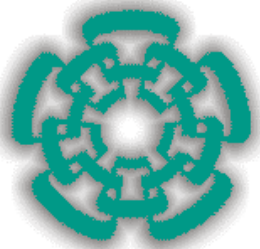


NiO: $d_{ox}(T,t)$

Ni: $d_{Ni}(T,t)$

vidrio





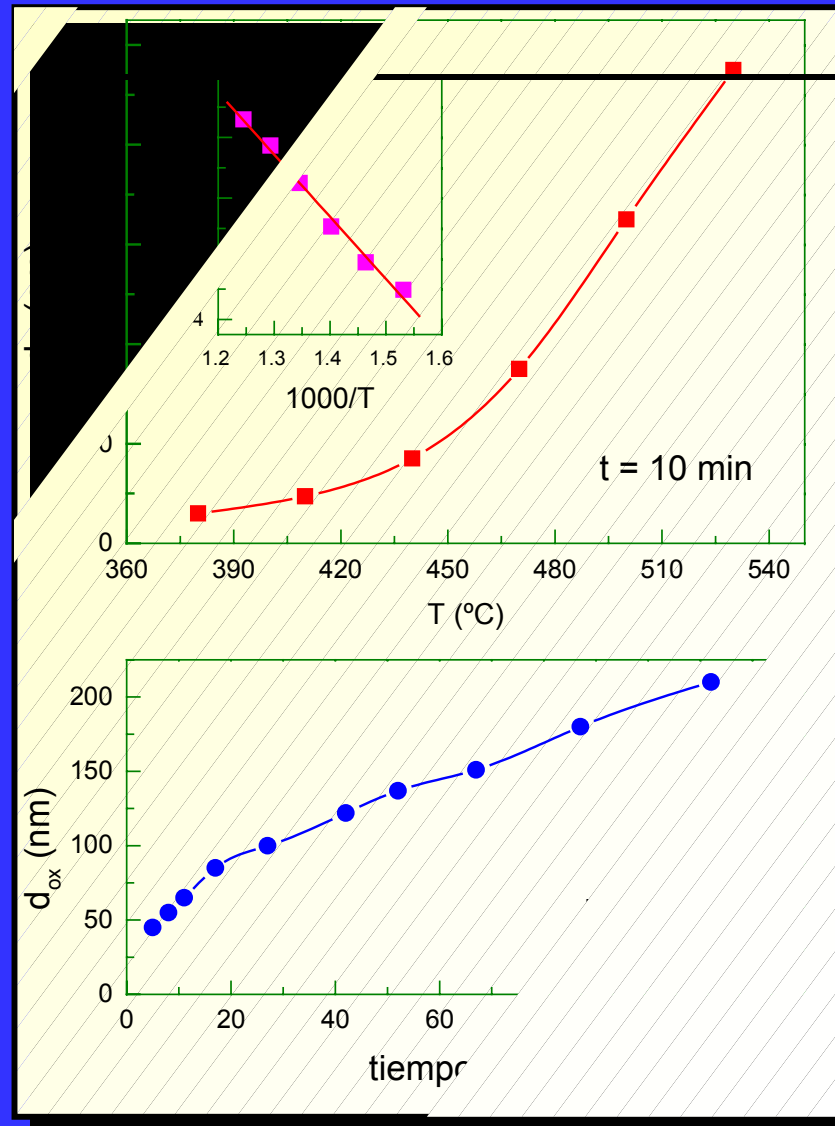
Oxidación de Níquel

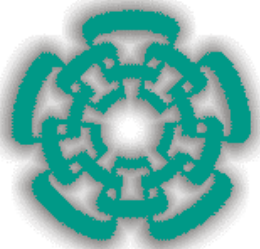
Ni: 125 nm
vidrio

NiO: $d_{ox}(T, t)$

Ni: $d_{Ni}(T, t)$

vidrio

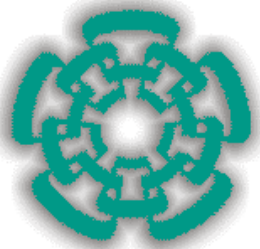




Sumario

El análisis de datos ópticos sobre un intervalo amplio de longitudes de onda permite determinar diferentes parámetros ópticos y microestructurales de la muestra.

Con lo anterior es posible estudiar el efecto de las variables del procesamiento sobre las cantidades de interés.



Incorporación de diferentes especies en los poros del SiO_2

